

6xxnm 800mW Diode Laser Source

Introduction

Modularized temperature-control IC and power-supplier IC, diode laser source achieved over-temperature protection, fiber-coupled output, with CW and pulse model output.



Tech Parameters (20°C)

Fiber Output P2 Integration Source	
Parameter	LOS-BLD-06xx-800m-C/P
Center Wavelength	635nm/650nm/670nm
Output Optical Capacity	0~800mW
Driving Power	220VAC ± 10%, 50 ~ 60Hz
Output Current Capacity	Max. 2V3A
Output Model	CW/Pulse
Pulse Model Frequency	0 ~ 10KHz
Output Interface	FC/SMA-905
Optical Fiber Parameter	400μm, 0.22
Operating Temperature	5 ~ 35°C
Operating Moisture	5% ~ 85% (No Condensation)
Storage Temperature	-10 ~ 60°C
Size	280*225*135 (mm)

Notice

1. Item notice: LOS(Item model)-BLD-**** (wavelength) -**** (output optical capacity) -C/P.
2. Customized service including center wavelength, output optical capacity, fiber parameters.
3. For more information, please contact Hi-Tech Optoelectronics Co., Ltd.



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